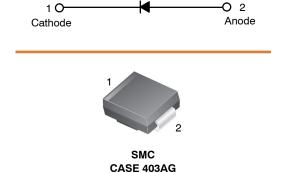


Fast Rectifiers ES3A - ES3J

Features

- For Surface Mount Applications
- Glass-Passivated Junction
- Low-Profile Package
- Easy Pick and Place
- Built-in Strain Relief
- Superfast Recovery Times for High Efficiency
- These Devices are Pb-Free and Halid Free



MARKING DIAGRAM



Z = Assembly Plant Code

X = Last Digit of Year of Manufacture
YY = Weekly Code of Manufacture
DDDD = Specific Device Code

ORDERING INFORMATION

Part Number	Device Code Marking	Package	Shipping [†]
ES3A	ES3A	DO-214AB (SMC)	3000 / Tape & Reel
ES3B	ES3B	(Pb-Free)	3000 / Tape & Reel
ES3C	ES3C		3000 / Tape & Reel
ES3D	ES3D		3000 / Tape & Reel
ES3J	ES3J		3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ES3A - ES3J

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

		Value					
Symbol	Parameter	ES3A	ES3B	ES3C	ES3D	ES3J	Unit
V _{RRM}	Maximum Repetitive Reverse Voltage	50	100	150	200	600	V
I _{F(AV)}	Average Rectified Forward Current, .375" Lead Length T _A = 75°C	3.0		Α			
I _{FSM}	Non-Repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine Wave	100		Α			
T _{STG}	Storage Temperature Range	-55 to +150		°C			
TJ	Operating Junction Temperature	-55 to +150		°C			

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Pa	Value	Unit	
P _D	Power Dissipation		1.66	W
$R_{ heta JA}$	Thermal Resistance,	Maximum Land Pattern: 16 x 16 mm	47	°C/W
	Junction to Ambient (Note 1)	Minimum Land Pattern: 2.6 x 3.2 mm	125	
$R_{ heta JL}$	Thermal Resistance,	Maximum Land Pattern: 16 x 16 mm	12	°C/W
	Junction to Lead (Note 1)	Minimum Land Pattern: 2.6 x 3.2 mm	16	

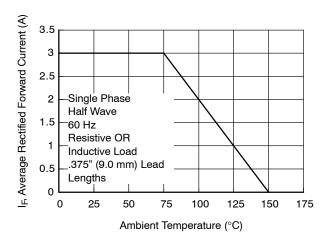
^{1.} Device mounted on FR-4 PCB 0.013 mm.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

		Value							
Symbol	Parameter	Conditions		ES3A	ES3B	ES3C	ES3D	ES3J	Unit
V _F	Maximum Forward Voltage	I _F = 3.0 A		0.95			1.70	V	
t _{rr}	Reverse Recovery Time	I _F = 0.5 A, I _R = 1.0 A	Тур.	20			35	ns	
		I _{RR} = 0.25 A	Max.	30			45	1	
I _R			T _A = 25°C		10				μΑ
at Rated V _R		T _A = 100°C		500					
C _T	Total Capacitance	V _R = 4.0 V, f = 1.0 MHz		45				pF	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

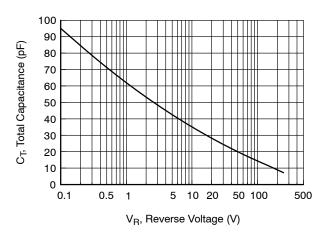
TYPICAL PERFORMANCE CHARACTERISTICS



100 ES3A-ES3D I_F, Forward Current (A) 10 ES3J 0.1 Pulse Width = 300 μs 2% Duty Cycle 0.01 0.6 8.0 1.6 1.0 1.2 1.8 0.4 1.4 V_F, Forward Voltage Drop (V)

Figure 1. Forward Current Derating Curve

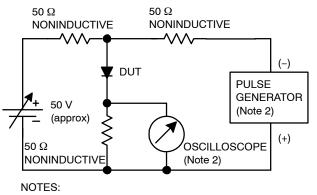
Figure 2. Forward Voltage Characteristics

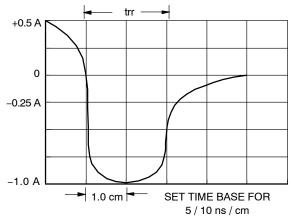


1000 $T_{\Delta} = 100^{\circ}C$ I_R, Reverse Current (μA) 100 T_A = 75°C 10 T_A = 25°C 0.1 0 20 40 80 100 120 140 Percent of Rated Peak Reverse Voltage (%)

Figure 3. Total Capacitance

Figure 4. Reverse Current vs. Reverse Voltage



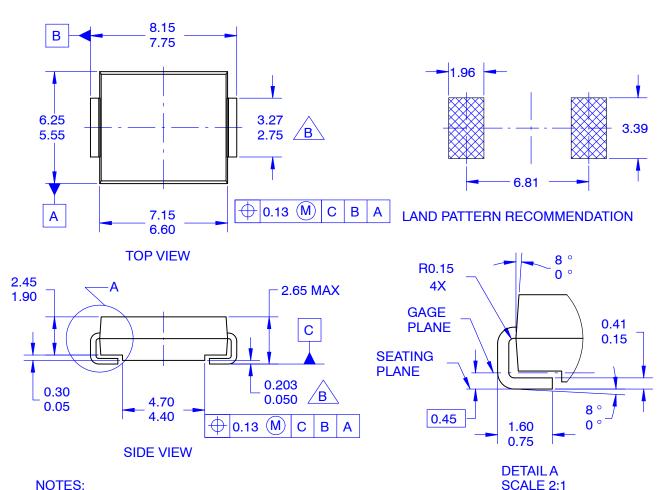


- 2. Rise time = 7.0 ns max; Input impedance = 1.0 M Ω 22 pF.
- 3. Rise time = 10 ns max; Source impedance = 50 Ω .

Figure 5. Reverse Recovery Time Characteristics and Test Circuit Diagram

SMC CASE 403AG ISSUE O

DATE 31 AUG 2016



A. EXCEPT WHERE NOTED, CONFORMS TO JEDEC DO-214, VARIATION AB

B

DOES NOT COMPLY TO JEDEC STD. VALUE

- C. ALL DIMENSIONS ARE IN MILLIMETERS
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR PROTRUSIONS.
- E. DIMENSIONS AND TOLERANCING AS PER ASME Y14.5-2009
- F. LAND PATTERN STANDARD: DIOM7957X241M

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